



Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



FEATURES

- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, V_{CEO} = 70 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

DESCRIPTION

The SFH610A and SFH6106 feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

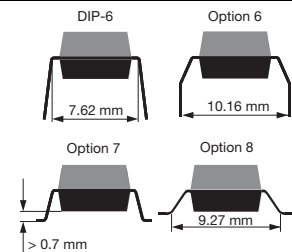
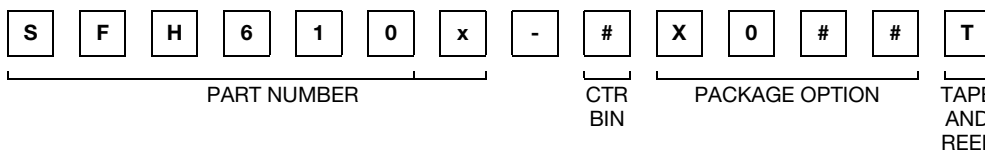
The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6 and option 8. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400 V_{RMS} or DC. Specifications subject to change.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- BSI IEC 60950; IEC 60065
- CSA 93751

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)				
	40 to 80	63 to 125	100 to 200	160 to 320	250 to 500
UL, BSI, CSA					
DIP-4	SFH610A-1	SFH610A-2	SFH610A-3	SFH610A-4	SFH610A-5
DIP-4, 400 mil	-	SFH610A-2X006	SFH610A-3X006	-	-
SMD-4	SFH6106-1T	SFH6106-2T	SFH6106-3T	SFH6106-4T	SFH6106-5T
SMD-4, option 7	-	-	SFH610A-3X007T	-	-
SMD-4, 400 mil, option 8	-	-	-	SFH610A-4X008T	-
VDE, UL, BSI, CSA (option 1)					
DIP-4	SFH610A-1X001	SFH610A-2X001	SFH610A-3X001	SFH610A-4X001	-
DIP-4, 400 mil	SFH610A-1X016	-	SFH610A-3X016	SFH610A-4X016	-
SMD-4	SFH6106-1X001T	SFH6106-2X001T	SFH6106-3X001T	SFH6106-4X001T	-
SMD-4, 400 mil, option 8	SFH610A-1X018T	-	-	-	-

Note

- For additional information on the available options refer to option information



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6	V
DC forward current		I _F	60	mA
Surge forward current	t ≤ 10 μs	I _{FSM}	2.5	A
Power dissipation		P _{diss}	100	mW
OUTPUT				
Collector emitter voltage		V _{CEO}	70	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		I _C	50	mA
	t _p ≤ 1.0 ms	I _C	100	mA
Power dissipation		P _{diss}	150	mW
COUPLER				
Storage temperature range		T _{stg}	-55 to +150	°C
Ambient temperature range		T _{amb}	-55 to +100	°C
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 60 mA		V _F	-	1.25	1.65	V
Reverse current	V _R = 6 V		I _R	-	0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz		C _O	-	13	-	pF
Thermal resistance			R _{thja}	-	750	-	K/W
OUTPUT							
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}	-	5.2	-	pF
Thermal resistance			R _{thja}	-	500	-	K/W
Collector emitter leakage current	V _{CE} = 10 V	SFH610A-1	I _{CEO}	-	2	50	nA
		SFH6106-1	I _{CEO}	-	2	50	nA
		SFH610A-2	I _{CEO}	-	2	50	nA
		SFH6106-2	I _{CEO}	-	2	50	nA
		SFH610A-3	I _{CEO}	-	5	100	nA
		SFH6106-3	I _{CEO}	-	5	100	nA
		SFH610A-4	I _{CEO}	-	5	100	nA
		SFH6106-4	I _{CEO}	-	5	100	nA
		SFH610A-5	I _{CEO}	-	5	100	nA
SFH6106-5	I _{CEO}	-	5	100	nA		
COUPLER							
Collector emitter saturation voltage	I _F = 10 mA, I _C = 2.5 mA		V _{CEsat}	-	0.25	0.4	V
Coupling capacitance	f = 1 MHz		C _C	-	0.4	-	pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	I _F = 10 mA, V _{CE} = 5.0 V	SFH610A-1	CTR	40	-	80	%
		SFH6106-1	CTR	40	-	80	%
		SFH610A-2	CTR	63	-	125	%
		SFH6106-2	CTR	63	-	125	%
		SFH610A-3	CTR	100	-	200	%
		SFH6106-3	CTR	100	-	200	%
		SFH610A-4	CTR	160	-	320	%
		SFH6106-4	CTR	160	-	320	%
	I _F = 1 mA, V _{CE} = 5 V	SFH610A-1	CTR	13	30	-	%
		SFH6106-1	CTR	13	30	-	%
		SFH610A-2	CTR	22	45	-	%
		SFH6106-2	CTR	22	45	-	%
		SFH610A-3	CTR	34	70	-	%
		SFH6106-3	CTR	34	70	-	%
		SFH610A-4	CTR	56	90	-	%
		SFH6106-4	CTR	56	90	-	%

SWITCHING CHARACTERISTICS													
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT						
NON-SATURATED													
Current	V _{CC} = 5 V, R _L = 75 Ω		I _F	-	10	-	mA						
Rise time	V _{CC} = 5 V, R _L = 75 Ω		t _r	-	2	-	μs						
Fall time	V _{CC} = 5 V, R _L = 75 Ω		t _f	-	2	-	μs						
Turn-on time	V _{CC} = 5 V, R _L = 75 Ω		t _{on}	-	3	-	μs						
Turn-off time	V _{CC} = 5 V, R _L = 75 Ω		t _{off}	-	2.3	-	μs						
Cut-off frequency	V _{CC} = 5 V		F _{CO}	-	250	-	kHz						
SATURATED													
Current		SFH610A-1	I _F	-	20	-	mA						
		SFH6106-1											
		SFH610A-2	I _F					10	-	mA			
		SFH6106-2											
		SFH610A-3	I _F								10	-	mA
		SFH6106-3											
		SFH610A-4	I _F										
SFH6106-4													
SATURATED													
Rise time		SFH610A-1	t _r	-	2	-	μs						
		SFH6106-1											
		SFH610A-2	t _r					3	-	μs			
		SFH6106-2											
		SFH610A-3	t _r								3	-	μs
		SFH6106-3											
SFH610A-4	t _r	4	-	μs									
SFH6106-4													



SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Fall time		SFH610A-1	t_f	-	11	-	μs
		SFH6106-1					
		SFH610A-2	t_f	-	14	-	μs
		SFH6106-2					
		SFH610A-3	t_f	-	14	-	μs
		SFH6106-3					
SFH610A-4	t_f	-	15	-	μs		
SFH6106-4							
Turn-on time		SFH610A-1	t_{on}	-	3	-	μs
		SFH6106-1					
		SFH610A-2	t_{on}	-	4.2	-	μs
		SFH6106-2					
		SFH610A-3	t_{on}	-	4.2	-	μs
		SFH6106-3					
SFH610A-4	t_{on}	-	6	-	μs		
SFH6106-4							
Turn-off time		SFH610A-1	t_{off}	-	18	-	μs
		SFH6106-1					
		SFH610A-2	t_{off}	-	23	-	μs
		SFH6106-2					
		SFH610A-3	t_{off}	-	23	-	μs
		SFH6106-3					
SFH610A-4	t_{off}	-	25	-	μs		
SFH6106-4							

Note

- All values presented are typical values.

SAFETY AND INSULATION RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, $t = 1 \text{ min}$	V_{ISO}	4420	V_{RMS}
Tested withstanding isolation voltage	According to UL1577, $t = 1 \text{ s}$	V_{ISO}	5300	V_{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V_{IOTM}	10 000	V
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V_{IORM}	890	V
Isolation resistance	$V_{IO} = 500 \text{ V}$, $T_{amb} = 25 \text{ }^\circ\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500 \text{ V}$, $T_{amb} = 100 \text{ }^\circ\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Output safety power		P_{SO}	400	mW
Input safety current		I_{SI}	275	mA
Input safety temperature		T_{SI}	175	$^\circ\text{C}$
Creepage distance	DIP-4 / SMD-4		≥ 7	mm
Clearance distance			≥ 7	mm
Creepage distance	DIP-4, 400 mil / SMD-4, 400 mil		≥ 8	mm
Clearance distance			≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

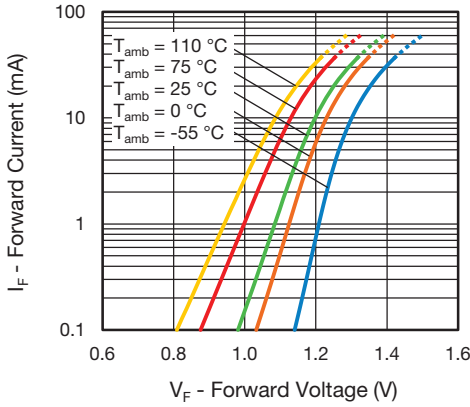


Fig. 1 - Forward Voltage vs. Forward Current



Fig. 4 - Normalized Current Transfer Ratio (non-saturated) vs. Ambient Temperature

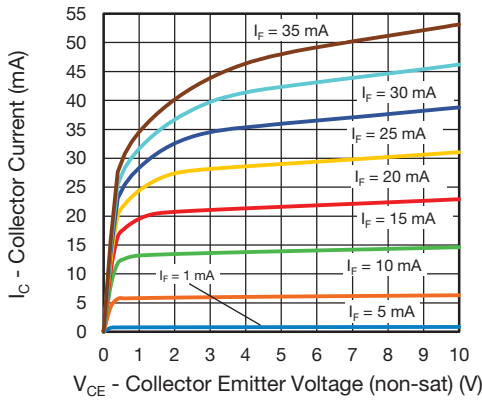


Fig. 2 - Collector Current vs. Collector Emitter Voltage (NS)

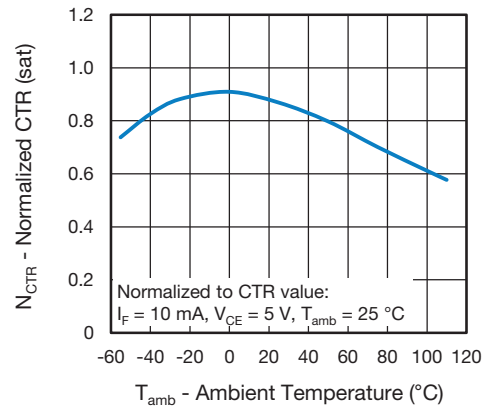


Fig. 5 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature

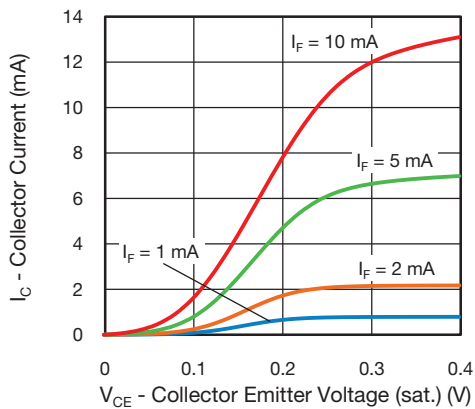


Fig. 3 - Collector Current vs. Collector Emitter Voltage (saturated)

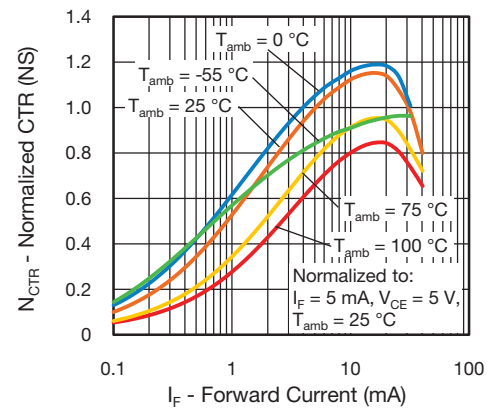


Fig. 6 - Normalized CTR (non-saturated) vs. Forward Current

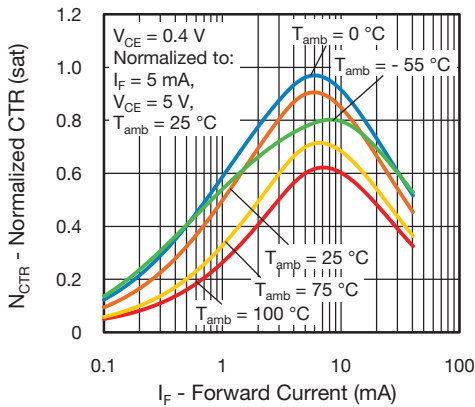


Fig. 7 - Normalized CTR (saturated) vs. Forward Current

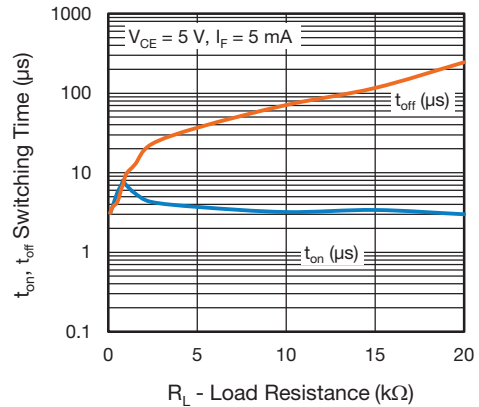


Fig. 10 - Switching Time vs. Load Resistance

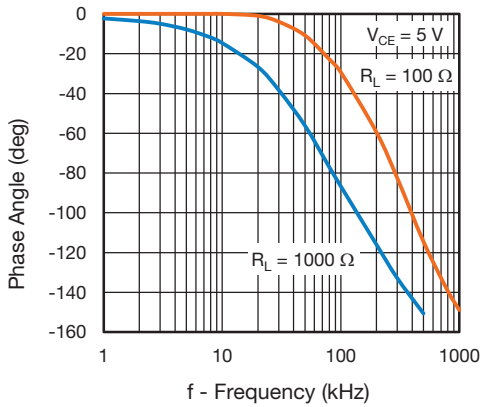


Fig. 8 - Phase Angle vs. Frequency

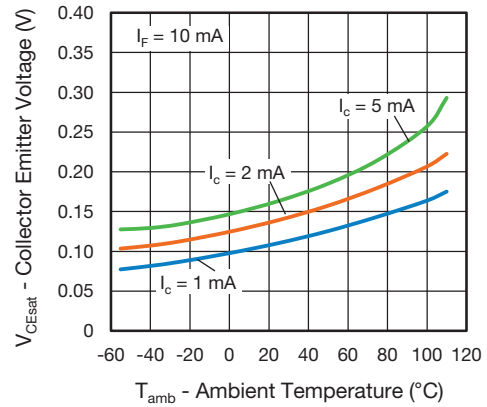


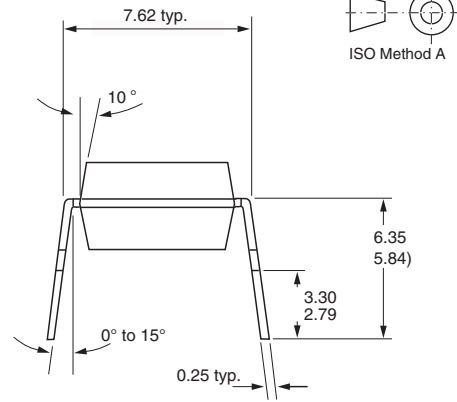
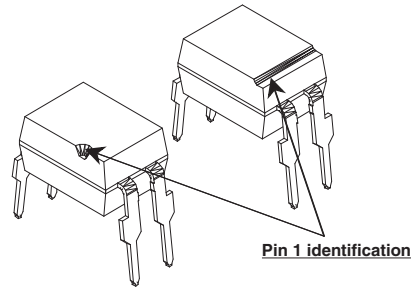
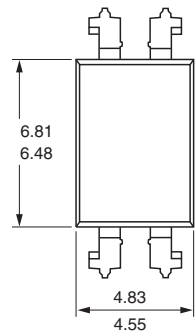
Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature (saturated)



Fig. 9 - CTR Frequency vs. Collector Current

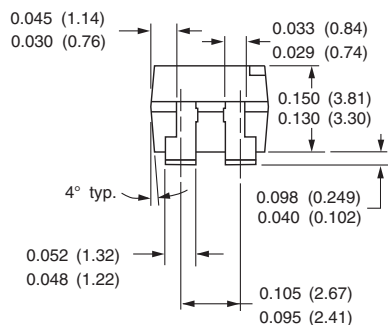
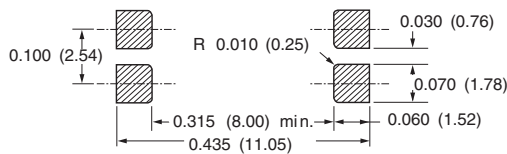


PACKAGE DIMENSIONS in inches (millimeters)

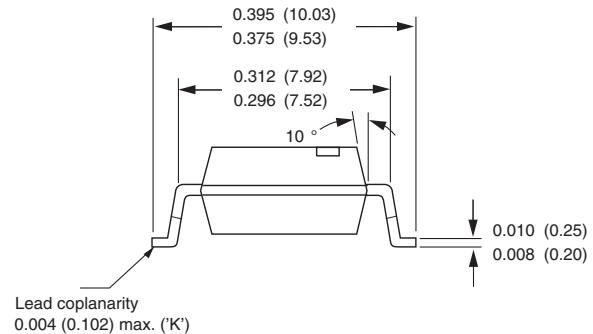


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SMD



i178029-2

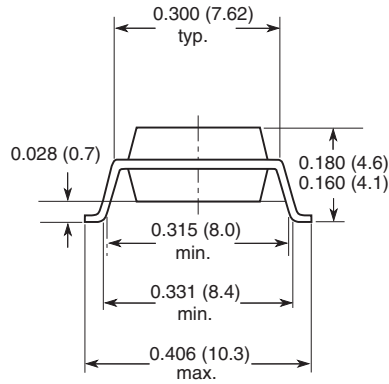




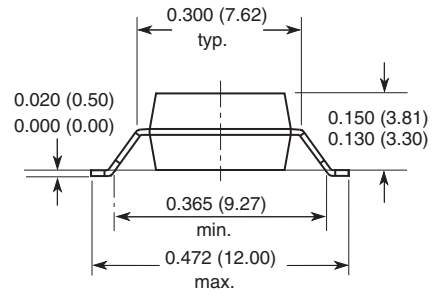
Option 6



Option 7



Option 8



18487



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